



+1.2V to +3.6V, 0.1 μ A, 100Mbps, 8-Channel Level Translators

MAX3013

General Description

The MAX3013 8-channel level translator provides the level shifting necessary to allow 100Mbps data transfer in a multivoltage system. Externally applied voltages, V_{CC} and V_L , set the logic levels on either side of the device. Logic signals present on the V_L side of the device appear as a higher voltage logic signal on the V_{CC} side of the device, and vice-versa.

The MAX3013 features an EN input that, when at logic low, places all inputs/outputs on both sides in tristate and reduces the V_{CC} and V_L supply currents to 0.1 μ A. This device operates at a guaranteed data rate of 100Mbps for $V_L > 1.8V$.

The MAX3013 accepts a V_{CC} voltage from +1.65V to +3.6V and a V_L voltage from +1.2V to ($V_{CC} - 0.4V$), making it ideal for data transfer between low-voltage ASICs/PLDs and higher voltage systems. The MAX3013 is available in 5 x 4 UCSP™, 20-pin 5mm x 5mm QFN, and 20-pin TSSOP packages.

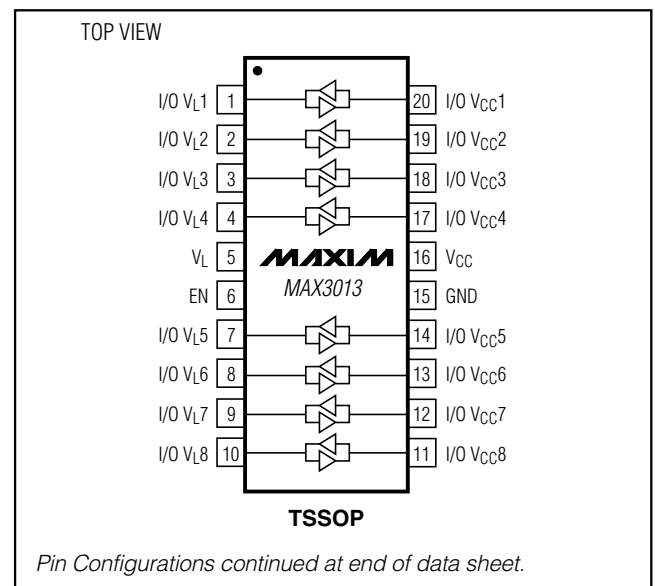
Applications

Low-Voltage ASIC Level Translation
Cell Phones
SPI™, MICROWIRE™ Level Translation
Portable POS Systems
Portable Communication Devices
GPS
Telecommunications Equipment

Features

- ◆ 100Mbps Guaranteed Data Rate
- ◆ Bidirectional Level Translation
- ◆ V_L Operation Down to +1.2V
- ◆ Ultra-Low 0.1 μ A Supply Current in Shutdown
- ◆ Low-Quiescent Current (0.1 μ A)
- ◆ UCSP, QFN, and TSSOP Packages

Pin Configurations



UCSP is a trademark of Maxim Integrated Products, Inc.
SPI is a trademark of Motorola, Inc.
MICROWIRE is a trademark of National Semiconductor Corp.

Typical Operating Circuit appears at end of data sheet.

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	NUMBER OF $V_L \rightarrow V_{CC}$ TRANSLATORS	NUMBER OF $V_L \leftarrow V_{CC}$ TRANSLATORS	DATA RATE (Mbps)
MAX3013EUP	-40°C to +85°C	20 TSSOP	8	8	100
MAX3013EBP-T	-40°C to +85°C	5 x 4 UCSP	8	8	100
MAX3013EGP	-40°C to +85°C	20 QFN-EP*	8	8	100

*EP = Exposed paddle.



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ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to GND.)

V _{CC}	-0.3V to +4V
V _L	-0.3V to +4V
I/O V _{CC}	-0.3V to (V _{CC} + 0.3V)
I/O V _L	-0.3V to (V _L + 0.3V)
EN.....	-0.3V to (V _L + 0.3V)
Short-Circuit Duration I/O V _L , I/O V _{CC} to GND.....	Continuous

Continuous Power Dissipation (T_A = +70°C)

20-Pin TSSOP (derate 11mW/°C above +70°C).....	879mW
5 x 4 UCSP (derate 10mW/°C above +70°C).....	800mW
20-Pin QFN (derate 20.0mW/°C above +70°C).....	1.60W
Operating Temperature Range.....	-40°C to +85°C
Junction Temperature.....	+150°C
Storage Temperature Range.....	-65°C to +150°C
Lead Temperature (soldering, 10s).....	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{CC} = +1.65V to +3.6V, V_L = +1.2V to (V_{CC} - 0.4V) (Note 1), EN = V_L, C_{IOV_L} ≤ 15pF, C_{IOV_{CC}} ≤ 40pF, T_A = T_{MIN} to T_{MAX}. Typical values are at V_{CC} = +3.3V, V_L = +1.8V, T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLIES						
V _L Supply Range	V _L		1.2		V _{CC} - 0.4	V
V _{CC} Supply Range	V _{CC}		1.65		3.6	V
Supply Current from V _{CC}	I _{QVCC}	I/O V _{CC} ₋ = 0, I/O V _L ₋ = 0 or I/O V _{CC} ₋ = V _{CC} , I/O V _L ₋ = V _L		0.1	1	µA
Supply Current from V _L	I _{QVL}	I/O V _{CC} ₋ = 0, I/O V _L ₋ = 0 or I/O V _{CC} ₋ = V _{CC} , I/O V _L ₋ = V _L		0.1	4	µA
		I/O V _{CC} ₋ = 0, I/O V _L ₋ = 0 or I/O V _{CC} ₋ = V _{CC} , I/O V _L ₋ = V _L , V _L < V _{CC} - 0.2V		0.1	100	
V _{CC} Tristate Output Mode Supply Current	I _{TS-VCC}	T _A = +25°C, EN = 0		0.03	1	µA
V _L Tristate Output Mode Supply Current	I _{TS-VL}	T _A = +25°C, EN = 0		0.1	0.2	µA
		T _A = +25°C, EN = 0, V _L = V _{CC} - 0.2V		1	2	
I/O Tristate Output Mode Leakage Current		T _A = +25°C, EN = 0,			0.15	µA
		T _A = +25°C, EN = 0, V _L = V _{CC} - 0.2V			30	
LOGIC-LEVEL THRESHOLDS						
I/O V _L ₋ Input-Voltage High	V _{IHL}		2/3 x			V
I/O V _L ₋ Input-Voltage Low	V _{ILL}				1/3 x	V
I/O V _{CC} ₋ Input-Voltage High	V _{IHC}		2/3 x			V
I/O V _{CC} ₋ Input-Voltage Low	V _{ILC}				1/3 x	V
EN Input-Voltage High	V _{IH}	T _A = +25°C	2/3 x			V

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ELECTRICAL CHARACTERISTICS (continued)

($V_{CC} = +1.65V$ to $+3.6V$, $V_L = +1.2V$ to $(V_{CC} - 0.4V)$ (Note 1), $EN = V_L$, $C_{IOVL} \leq 15pF$, $C_{IOVCC} \leq 40pF$, $T_A = T_{MIN}$ to T_{MAX} . Typical values are at $V_{CC} = +3.3V$, $V_L = +1.8V$, $T_A = +25^\circ C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
EN Input-Voltage Low	V_{IL}	$T_A = +25^\circ C$			$1/3 \times V_L$	V
EN Input Current		$T_A = +25^\circ C$			± 5	μA
I/O V_L _ Output-Voltage High	V_{OHL}	I/O V_L _ source current = $20\mu A$	$2/3 \times V_L$			V
I/O V_L _ Output-Voltage Low	V_{OLL}	I/O V_L _ sink current = $20\mu A$			$1/3 \times V_L$	V
I/O V_{CC} _ Output-Voltage High	V_{OHC}	I/O V_{CC} _ source current = $20\mu A$	$2/3 \times V_{CC}$			V
I/O V_{CC} _ Output-Voltage Low	V_{OLC}	I/O V_{CC} _ sink current = $20\mu A$			$1/3 \times V_{CC}$	V

TIMING CHARACTERISTICS

($V_{CC} = +1.65V$ to $+3.6V$, $V_L = +1.2V$ to $(V_{CC} - 0.4V)$ (Note 1), $EN = V_L$, $C_{IOVL} \leq 15pF$, $C_{IOVCC} \leq 40pF$, $T_A = T_{MIN}$ to T_{MAX} . Typical values are at $V_{CC} = +3.3V$, $V_L = +1.8V$, $T_A = +25^\circ C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
I/O V_{CC} _ Rise Time	t_{RVCC}	$C_{IOVCC} = 15pF$, Figure 1			2.5	ns
		$C_{IOVCC} = 20pF$, Figure 1			3	
		$C_{IOVCC} = 40pF$, Figure 1			4	
I/O V_{CC} _ Fall Time	t_{FVCC}	$C_{IOVCC} = 15pF$, Figure 1			2.5	ns
		$C_{IOVCC} = 20pF$, Figure 1			3	
		$C_{IOVCC} = 40pF$, Figure 1			4	
I/O V_{CC} _ One-Shot Output					18.5	Ω
I/O V_L _ Rise Time	t_{RVL}	$C_{IOVL} = 15pF$, Figure 2			2.5	ns
I/O V_L _ Fall Time	t_{FVL}	$C_{IOVL} = 15pF$, Figure 2			2.5	ns
I/O V_L _ One-Shot Output Impedance					12.5	Ω
Propagation Delay (Driving I/O V_L)	I/O _{VL-VCC}	$C_{IOVCC} = 15pF$, Figure 1			6.5	ns

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TIMING CHARACTERISTICS (continued)

($V_{CC} = +1.65V$ to $+3.6V$, $V_L = +1.2V$ to $(V_{CC} - 0.4V)$ (Note 1), $EN = V_L$, $C_{IOVL} \leq 15pF$, $C_{IOVCC} \leq 40pF$, $T_A = T_{MIN}$ to T_{MAX} . Typical values are at $V_{CC} = +3.3V$, $V_L = +1.8V$, $T_A = +25^\circ C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Propagation Delay (Driving I/O $V_{CC_}$)	I/O_{VCC-VL}	$C_{IOVL} = 15pF$, Figure 2			6	ns
Part-to-Part Skew	t_{PPSKEW}	$C_{IOVCC} = 15pF$, $C_{IOVL} = 15pF$, $V_{CC} = 2.5V$, $V_L = 1.8V$ (Note 3)			4	ns
Propagation Delay from I/O V_L to I/O $V_{CC_}$ after EN	t_{EN-VCC}	$C_{IOVCC} = 15pF$, Figure 3			1000	ns
Propagation Delay from I/O $V_{CC_}$ to I/O V_L after EN	t_{EN-VL}	$C_{IOVL} = 15pF$, Figure 4			1000	ns
Maximum Data Rate		$C_{IOVCC} = 15pF$, $C_{IOVL} = 15pF$, $V_L > 1.8V$	100			Mbps
		$C_{IOVCC} = 15pF$, $C_{IOVL} = 15pF$, $V_L > 1.2V$	80			

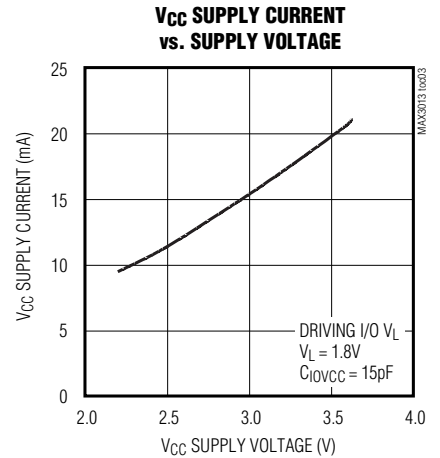
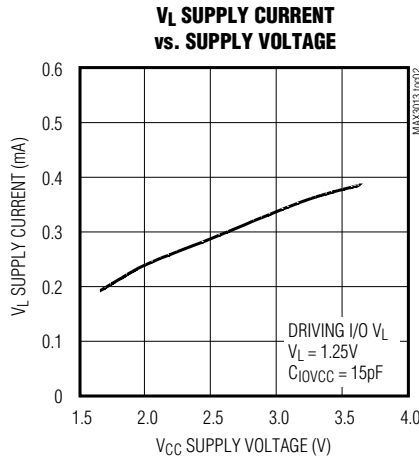
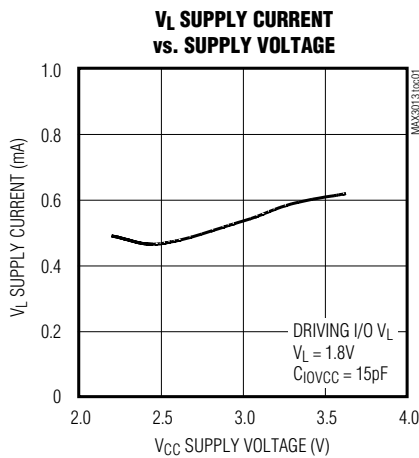
Note 1: V_L must be less than or equal to $V_{CC} - 0.4V$ during normal operation. However, V_L can be greater than $V_{CC} - 0.4V$ during starting up and shutting down conditions.

Note 2: All units are 100% production tested at $T_A = +25^\circ C$. Limits over the operating temperature range are guaranteed by design and not production tested.

Note 3: Not production tested. Guaranteed by design.

Typical Operating Characteristics

(Data rate = 100Mbps, $V_{CC} = 3.3V$, $V_L = 1.8V$, $T_A = +25^\circ C$, unless otherwise noted.)

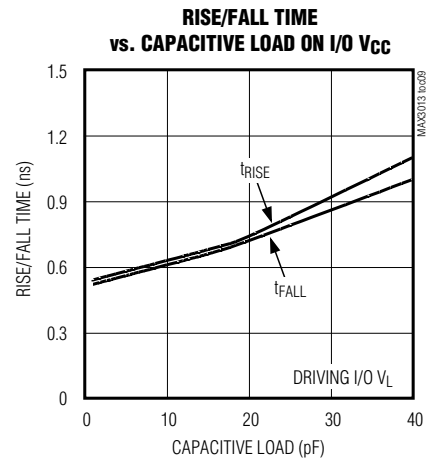
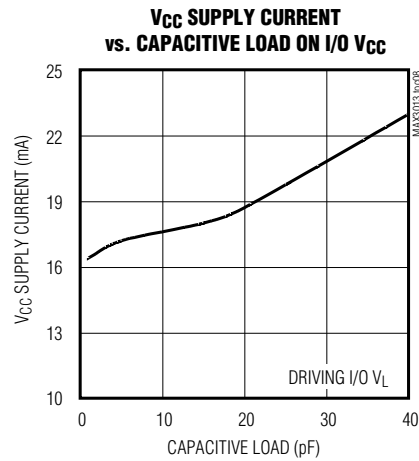
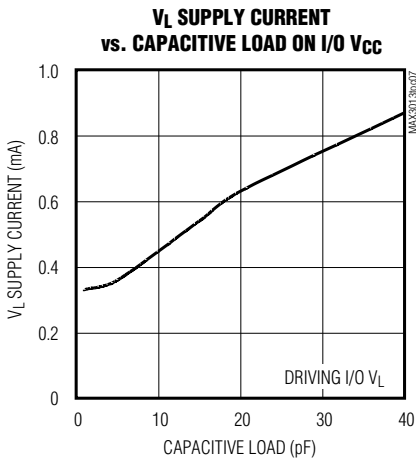
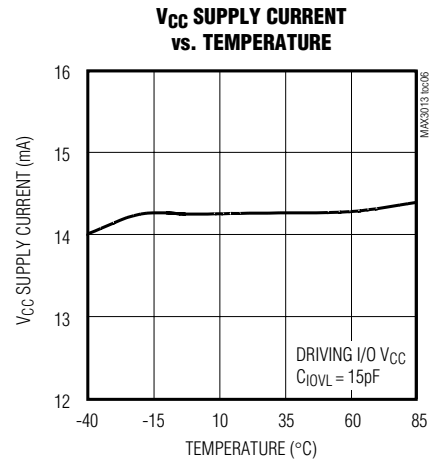
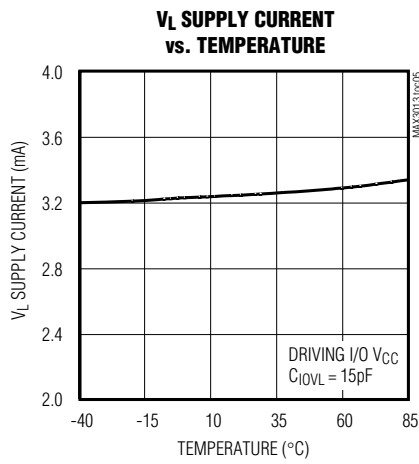
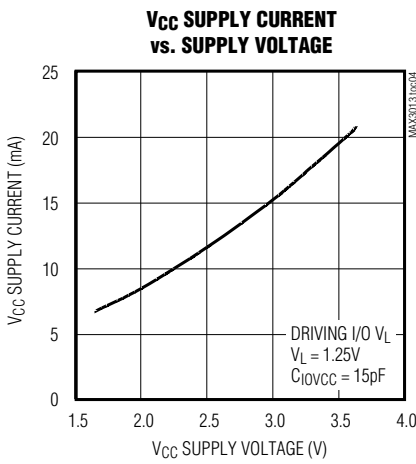


+1.2V to +3.6V, 0.1μA, 100Mbps, 8-Channel Level Translators

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Typical Operating Characteristics (continued)

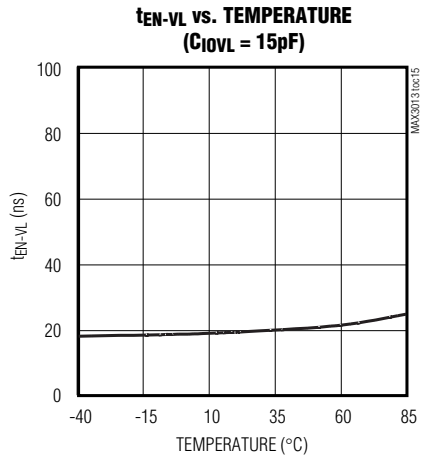
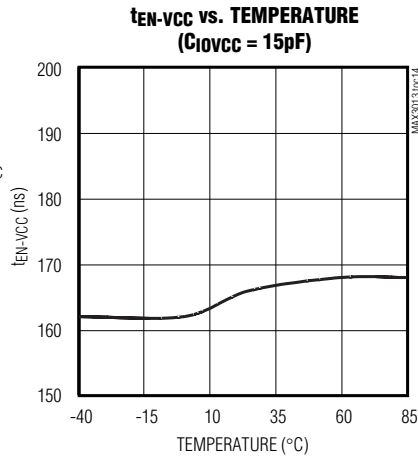
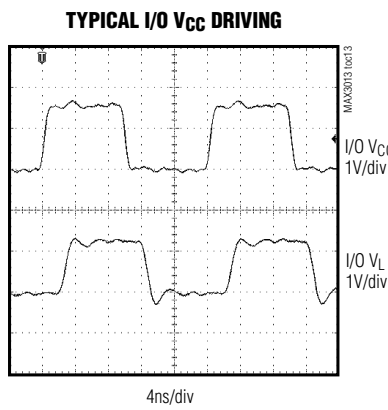
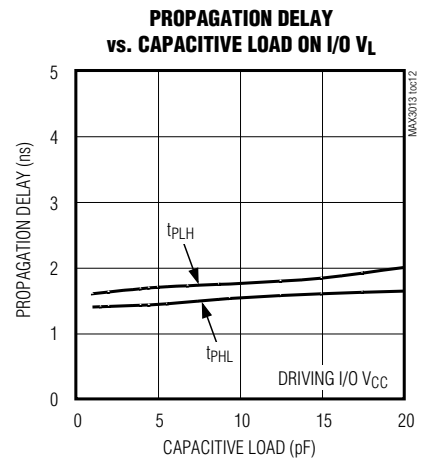
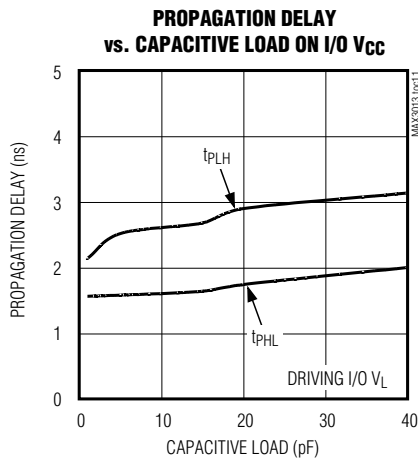
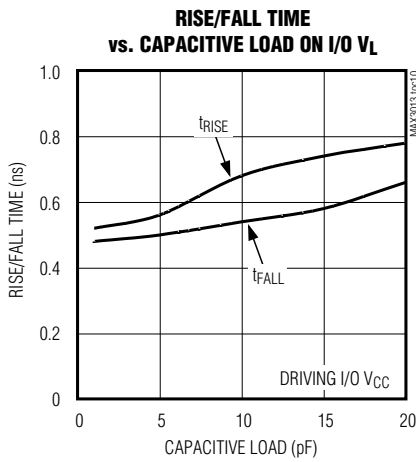
(Data rate = 100Mbps, $V_{CC} = 3.3V$, $V_L = 1.8V$, $T_A = +25^\circ C$, unless otherwise noted.)



+1.2V to +3.6V, 0.1μA, 100Mbps, 8-Channel Level Translators

Typical Operating Characteristics (continued)

(Data rate = 100Mbps, $V_{CC} = 3.3V$, $V_L = 1.8V$, $T_A = +25^\circ C$, unless otherwise noted.)



+1.2V to +3.6V, 0.1μA, 100Mbps, 8-Channel Level Translators

Pin Description

PIN		BUMP	NAME	FUNCTION
TSSOP	QFN	UCSP		
1	18	B1	I/O V _L 1	Input/Output 1, Referenced to V _L
2	19	A1	I/O V _L 2	Input/Output 2, Referenced to V _L
3	20	B2	I/O V _L 3	Input/Output 3, Referenced to V _L
4	1	A2	I/O V _L 4	Input/Output 4, Referenced to V _L
5	2	A3	V _L	V _L Input Voltage, +1.2V ≤ V _L ≤ (V _{CC} - 0.4V). Bypass V _L to GND with a 0.1μF capacitor.
6	3	A4	EN	Enable Input. If EN is pulled low, all inputs/outputs are in tristate. Drive EN high (V _L) for normal operation.
7	4	B3	I/O V _L 5	Input/Output 5, Referenced to V _L
8	5	A5	I/O V _L 6	Input/Output 6, Referenced to V _L
9	6	B4	I/O V _L 7	Input/Output 7, Referenced to V _L
10	7	B5	I/O V _L 8	Input/Output 7, Referenced to V _L
11	8	C5	I/O V _{CC} 8	Input/Output 8, Referenced to V _{CC}
12	9	C4	I/O V _{CC} 7	Input/Output 7, Referenced to V _{CC}
13	10	D5	I/O V _{CC} 6	Input/Output 6, Referenced to V _{CC}
14	11	C3	I/O V _{CC} 5	Input/Output 5, Referenced to V _{CC}
15	12	D4	GND	Ground
16	13	D3	V _{CC}	V _{CC} Input Voltage, +1.65V ≤ V _{CC} ≤ +3.6V. Bypass V _{CC} to GND with a 0.1μF capacitor.
17	14	D2	I/O V _{CC} 4	Input/Output 4, Referenced to V _{CC}
18	15	C2	I/O V _{CC} 3	Input/Output 3, Referenced to V _{CC}
19	16	D1	I/O V _{CC} 2	Input/Output 2, Referenced to V _{CC}
20	17	C1	I/O V _{CC} 1	Input/Output 1, Referenced to V _{CC}

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**+1.2V to +3.6V, 0.1μA, 100Mbps,
8-Channel Level Translators**

Test Circuits/Timing Diagrams

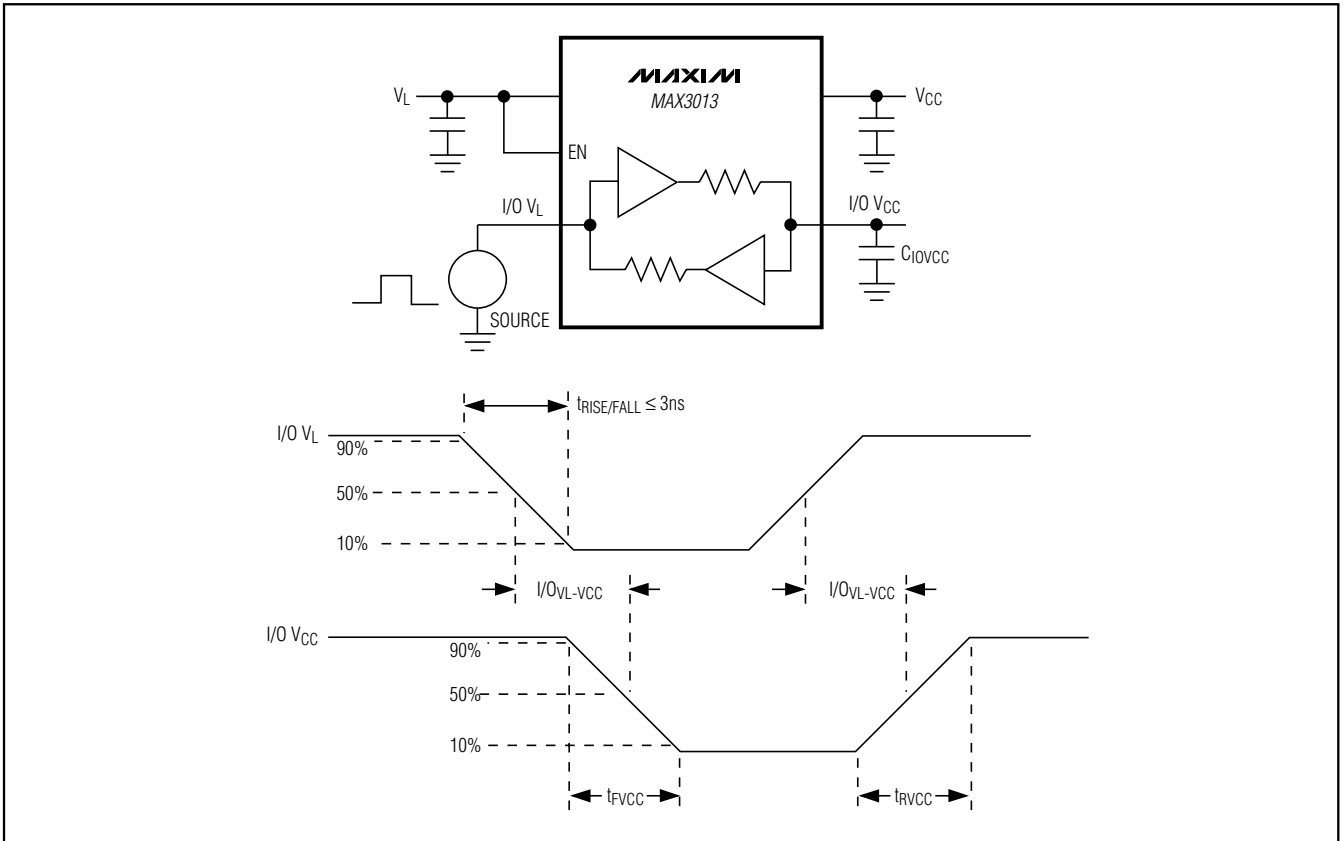


Figure 1. Driving I/O V_L Test Circuit and Timing

+1.2V to +3.6V, 0.1 μ A, 100Mbps, 8-Channel Level Translators

Test Circuits/Timing Diagrams (continued)

MAX3013

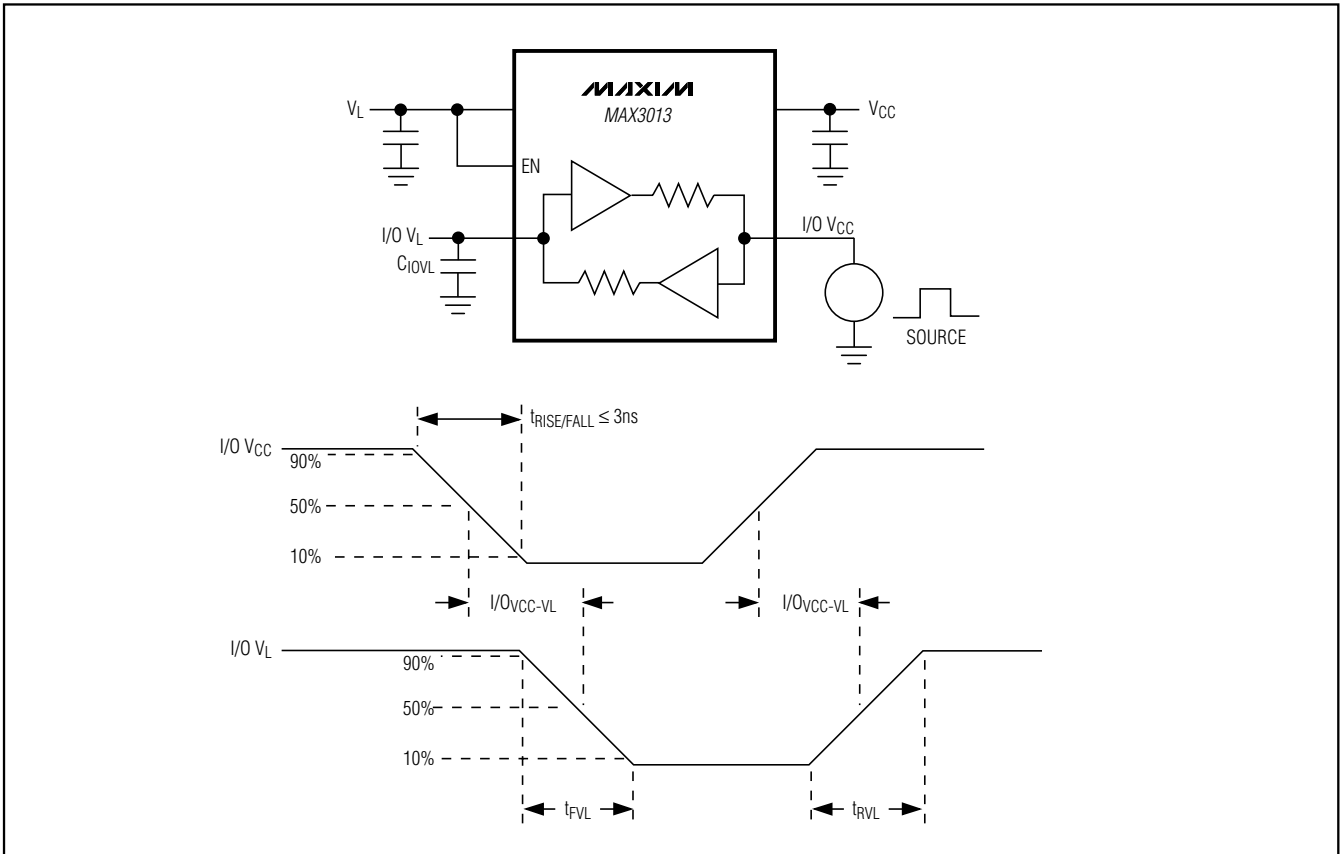


Figure 2. Driving I/O VCC Test Circuit and Timing

**+1.2V to +3.6V, 0.1µA, 100Mbps,
8-Channel Level Translators**

Test Circuits/Timing Diagrams (continued)

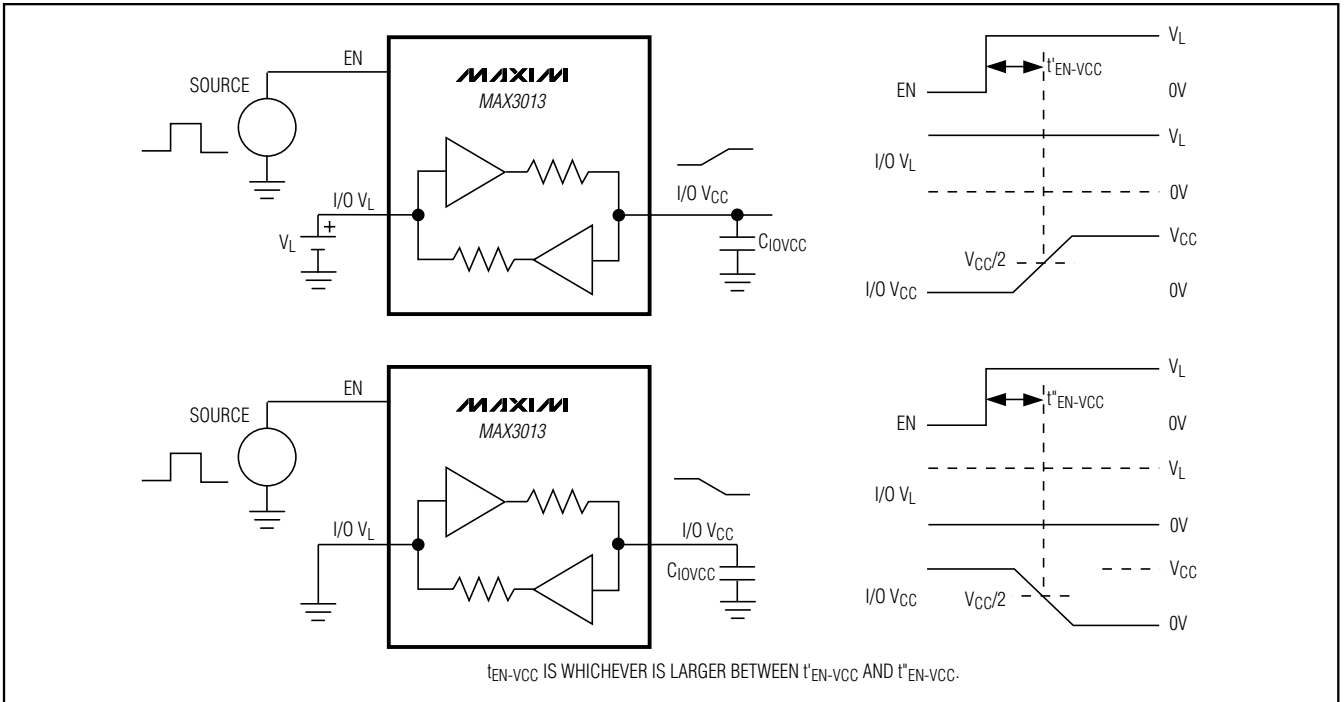


Figure 3. Propagation Delay from I/O VL to I/O VCC after EN

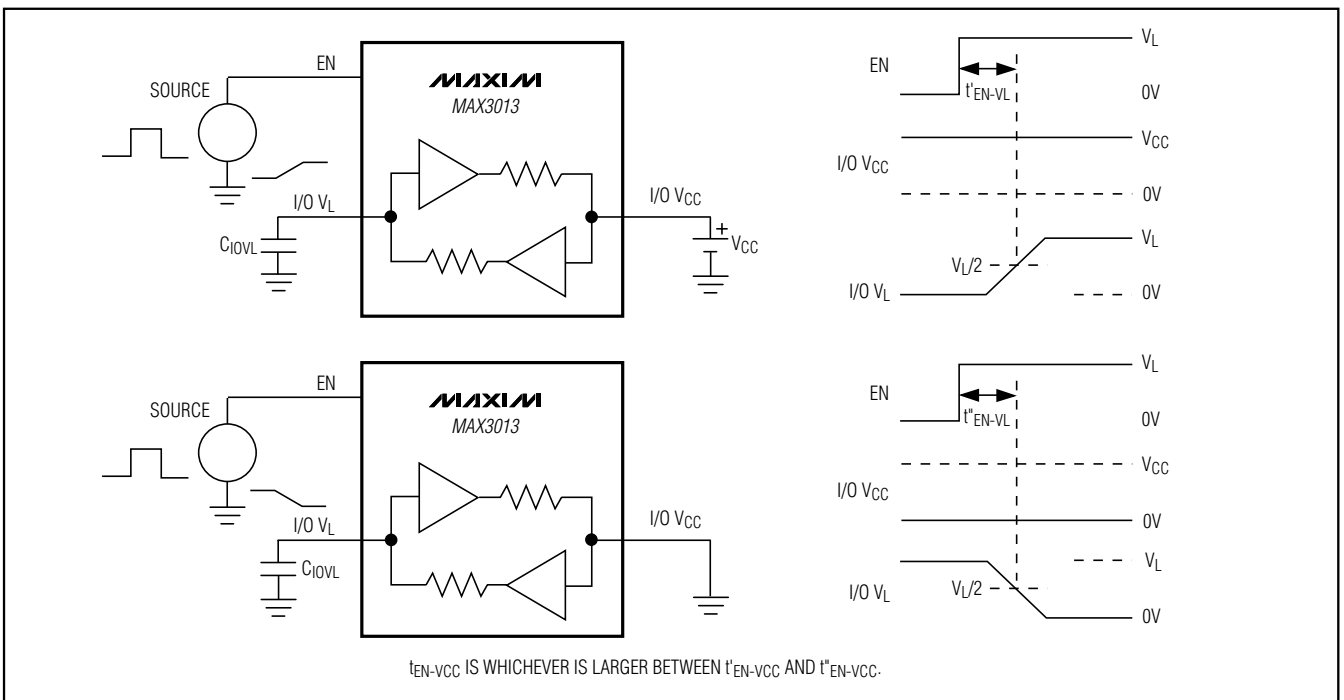


Figure 4. Propagation Delay from I/O VCC to I/O VL after EN

+1.2V to +3.6V, 0.1μA, 100Mbps, 8-Channel Level Translators

Detailed Description

The MAX3013 logic-level translator provides the level shifting necessary to allow 100Mbps data transfer in a multivoltage system. Externally applied voltages, V_{CC} and V_L , set the logic levels on either side of the device. Logic signals present on the V_L side of the device appear as a higher voltage logic signal on the V_{CC} side of the device, and vice-versa. The MAX3013 bidirectional level translator allows data translation in either direction ($V_L \leftrightarrow V_{CC}$) on any single data line. The MAX3013 accepts V_L from +1.2V to ($V_{CC} - 0.4V$) and operate with V_{CC} from +1.65V to +3.6V, making it ideal for data transfer between low-voltage ASICs/PLDs and higher voltage systems.

The MAX3013 features an input enable mode (EN) that reduces V_{CC} and V_L supply currents to 0.1μA, when in tristate mode. This device operates at a guaranteed data rate of 100Mbps for $V_L > +1.8V$.

Level Translation

For proper operation, ensure that $+1.65V \leq V_{CC} \leq +3.6V$, $+1.2V \leq V_L \leq (V_{CC} - 0.4V)$. During power-up sequencing, $V_L \geq V_{CC}$ does not damage the device. During power-supply sequencing, when V_{CC} is floating and V_L is powering up, up to 40mA current can be sourced to each load on the V_L side, yet the device does not latch up. The maximum data rate depends heavily on the load capacitance (see the *Typical Operating Characteristics*, Rise/Fall Times), output impedance of the driver, and the operating voltage range (see the *Timing Characteristics*).

Input Driver Requirements

The MAX3013 architecture is based on a one-shot accelerator output stage (see Figure 5). Accelerator output stages are always in tristate mode except when there is a transition on any of the translators on the input side, either I/O V_L or I/O V_{CC} . Then, a short pulse is generated during which the accelerator output stages become active and charge/discharge the capacitances at the I/Os. Due to its bidirectional nature, both input stages become active during the one-shot pulse. This can lead to some current feeding into the external source that is driving the translator. However, this behavior helps to speed up the transition on the driven side.

For proper operation, the external driver must meet the following conditions: $<25\Omega$ output impedance and $>20mA$ output current. Figure 6 shows a graph of Typical Input Current vs. Input Voltage.

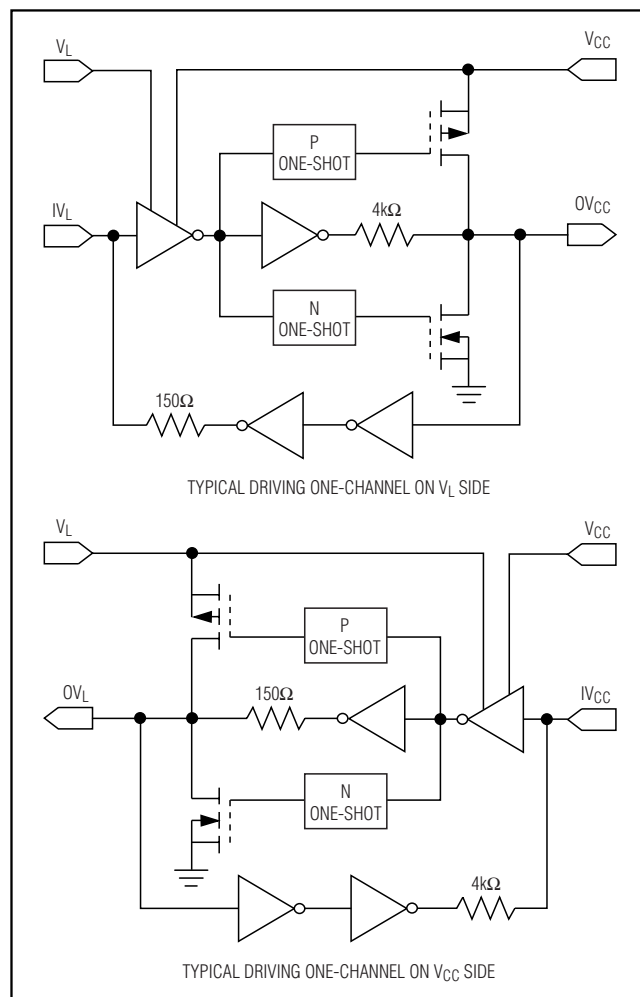


Figure 5. MAX3013 Simplified Diagram (1 I/O line)

Output Load Requirements

The MAX3013 I/O was designed to drive CMOS inputs. Do not load the I/O lines with a resistive load less than 25kΩ. Also, do not place an RC circuit at the input of the MAX3013 to slow down the edges. If a slower data rate is required, please see the MAX3000E/MAX3001E logic-level translator.

For I²C™ level translation, please refer to the MAX3372E–MAX3379E/MAX3390E–MAX3393E data sheet.

I²C is a trademark of Philips Corp. Purchase of I²C components of Maxim Integrated Products, Inc. or one of its sublicensed Associated Companies, conveys a license under the Philips I²C Patent Rights to use these components in an I²C system, provided that the system conforms to the I²C Standard Specification as defined by Philips.

+1.2V to +3.6V, 0.1µA, 100Mbps, 8-Channel Level Translators

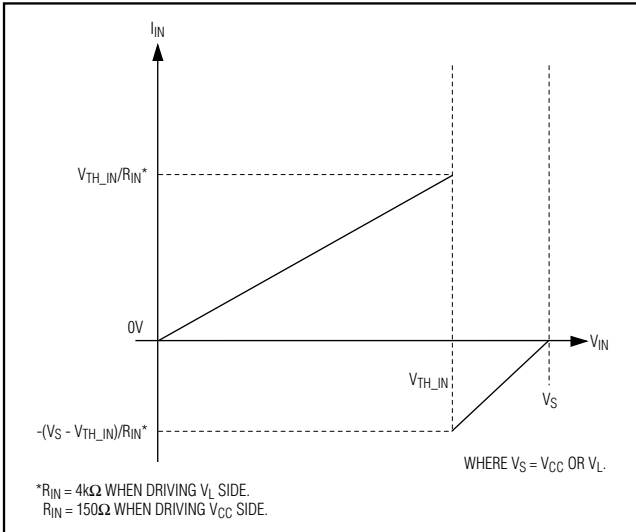


Figure 6. Typical I_{IN} vs. V_{IN}

Enable Input (EN)

The MAX3013 features an EN input. Pull EN low to set the MAX3013 I/O on both sides in tristate output mode. Drive EN to logic high (V_L) for normal operation.

Applications Information

Power-Supply Decoupling

To reduce ripple and the chance of introducing data errors, bypass V_L and V_{CC} to ground with a 0.1µF ceramic capacitor. Place the bypass capacitors as close to the power-supply input pins as possible.

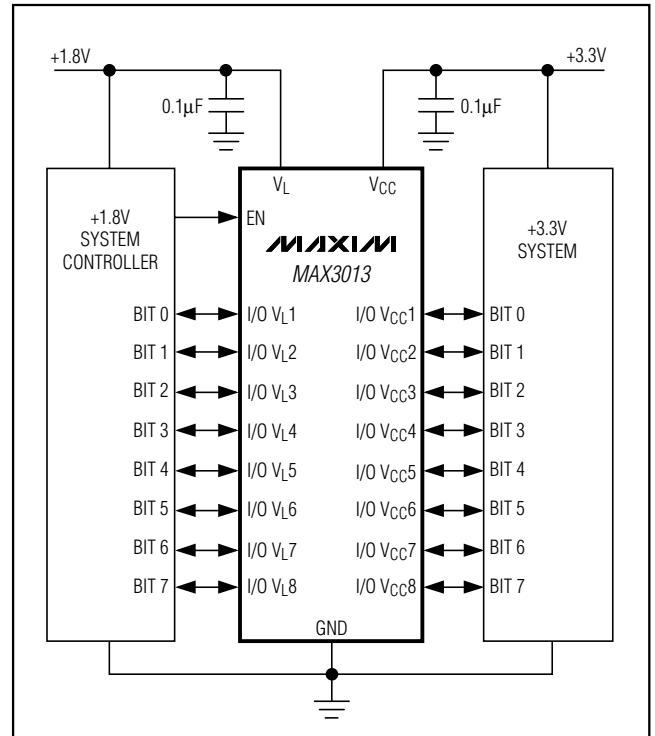
8-Bit Bus Translation

The MAX3013 level-shifts the data present on the I/O line between +1.2V to +3.6V, making it ideal for level translation between a low-voltage ASIC and a higher voltage system. The *Typical Operating Circuit* shows the MAX3013 bidirectional translator in an 8-bit bus level translation from a 1.8V system to a 3.3V system and vice versa.

Unidirectional vs. Bidirectional Level Translator

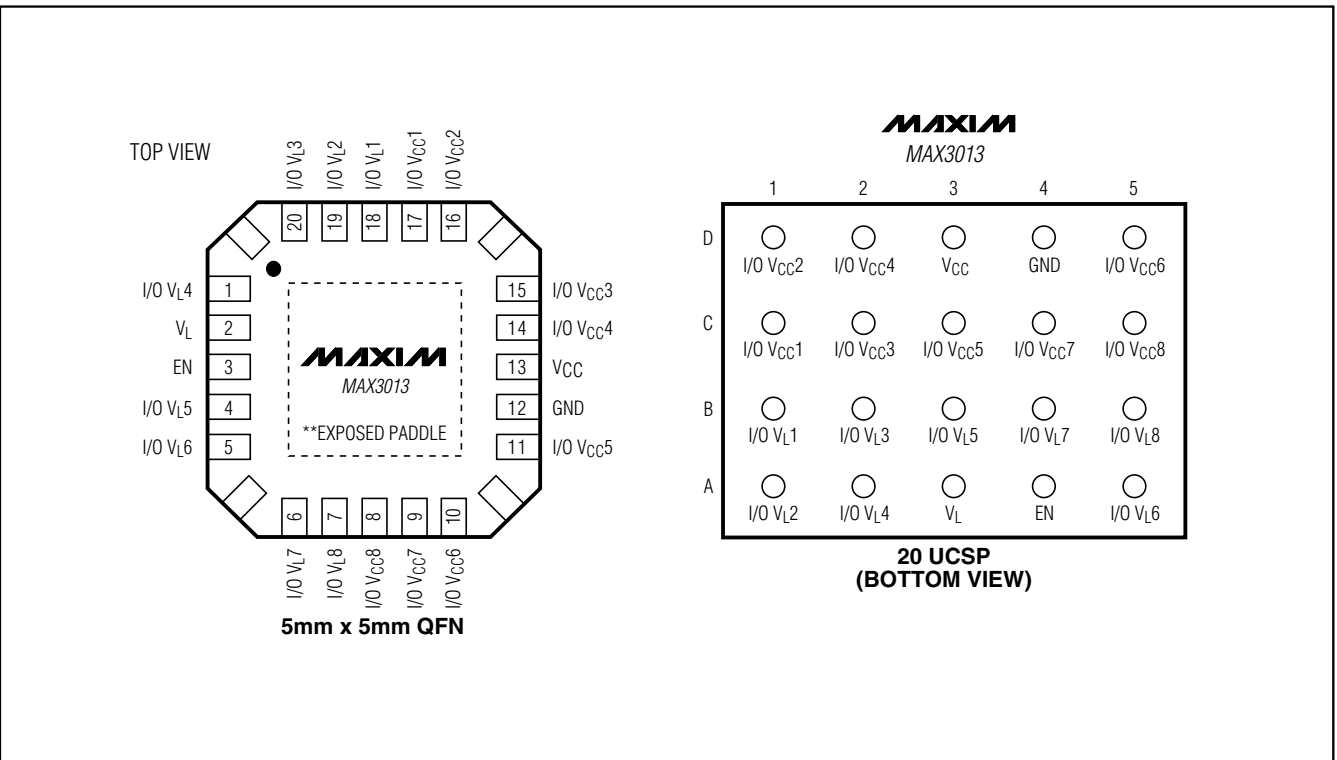
The MAX3013 bidirectional translator can operate as a unidirectional device to translate signals without inversion. This device provides the smallest solution (UCSP package) for unidirectional level translation without inversion.

Typical Operating Circuit



+1.2V to +3.6V, 0.1µA, 100Mbps, 8-Channel Level Translators

Pin Configurations (continued)



MAX3013

Chip Information

TRANSISTOR COUNT: 1447

PROCESS: BICMOS

+1.2V to +3.6V, 0.1µA, 100Mbps, 8-Channel Level Translators

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)

SYMBOL	COMMON DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	—	1.10	—	.043
A ₁	0.05	0.15	.002	.006
A ₂	0.85	0.95	.033	.037
b	0.19	0.30	.007	.012
b ₁	0.19	0.25	.007	.010
c	0.09	0.20	.004	.008
c ₁	0.09	0.14	.004	.006
D	SEE VARIATIONS		SEE VARIATIONS	
E	4.30	4.50	.169	.177
e	0.65 BSC		.026 BSC	
H	6.25	6.55	.246	.258
L	0.50	0.70	.020	.028
N	SEE VARIATIONS		SEE VARIATIONS	
α	0°	8°	0°	8°

JEDEC	N	VARIATIONS				
		MILLIMETERS		INCHES		
		MIN.	MAX.	MIN.	MAX.	
AB-1	14	D	4.90	5.10	.193	.201
AB	16	D	4.90	5.10	.193	.201
AC	20	D	6.40	6.60	.252	.260
AD	24	D	7.70	7.90	.303	.311
AE	28	D	9.60	9.80	.378	.386

NOTES:

- DIMENSIONS D AND E DO NOT INCLUDE FLASH
- MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15mm PER SIDE
- CONTROLLING DIMENSION: MILLIMETER
- MEETS JEDEC OUTLINE MO-153. SEE JEDEC VARIATIONS TABLE
- 'N' REFERS TO NUMBER OF LEADS
- THE LEAD TIPS MUST LIE WITHIN A SPECIFIED ZONE. THIS TOLERANCE ZONE IS DEFINED BY TWO PARALLEL PLANES. ONE PLANE IS THE SEATING PLANE, DATUM [-C-]; THE OTHER PLANE IS AT THE SPECIFIED DISTANCE FROM [-C-] IN THE DIRECTION INDICATED

TSSOP4, 4.0mm, EPS

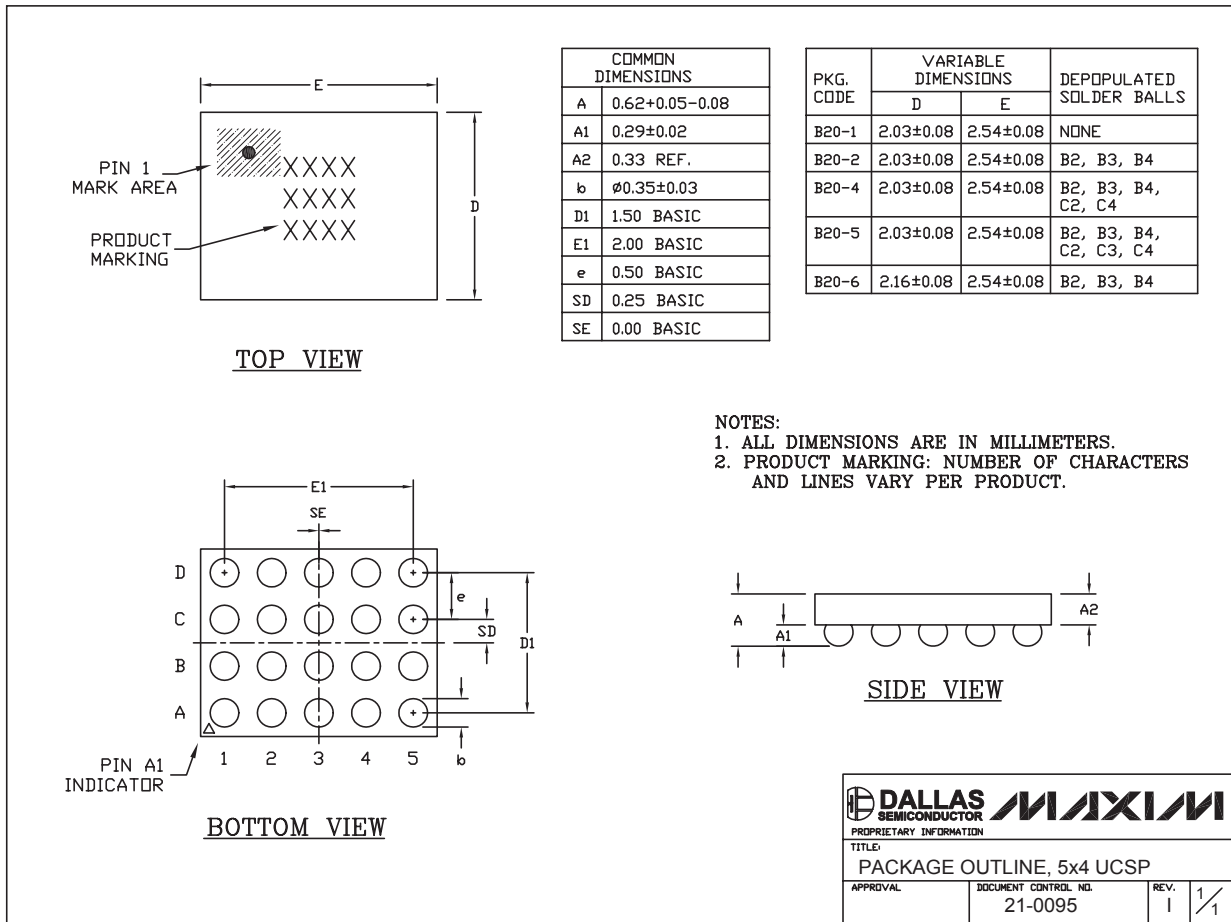
+1.2V to +3.6V, 0.1µA, 100Mbps, 8-Channel Level Translators

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)

5x4 UCSP:EPS

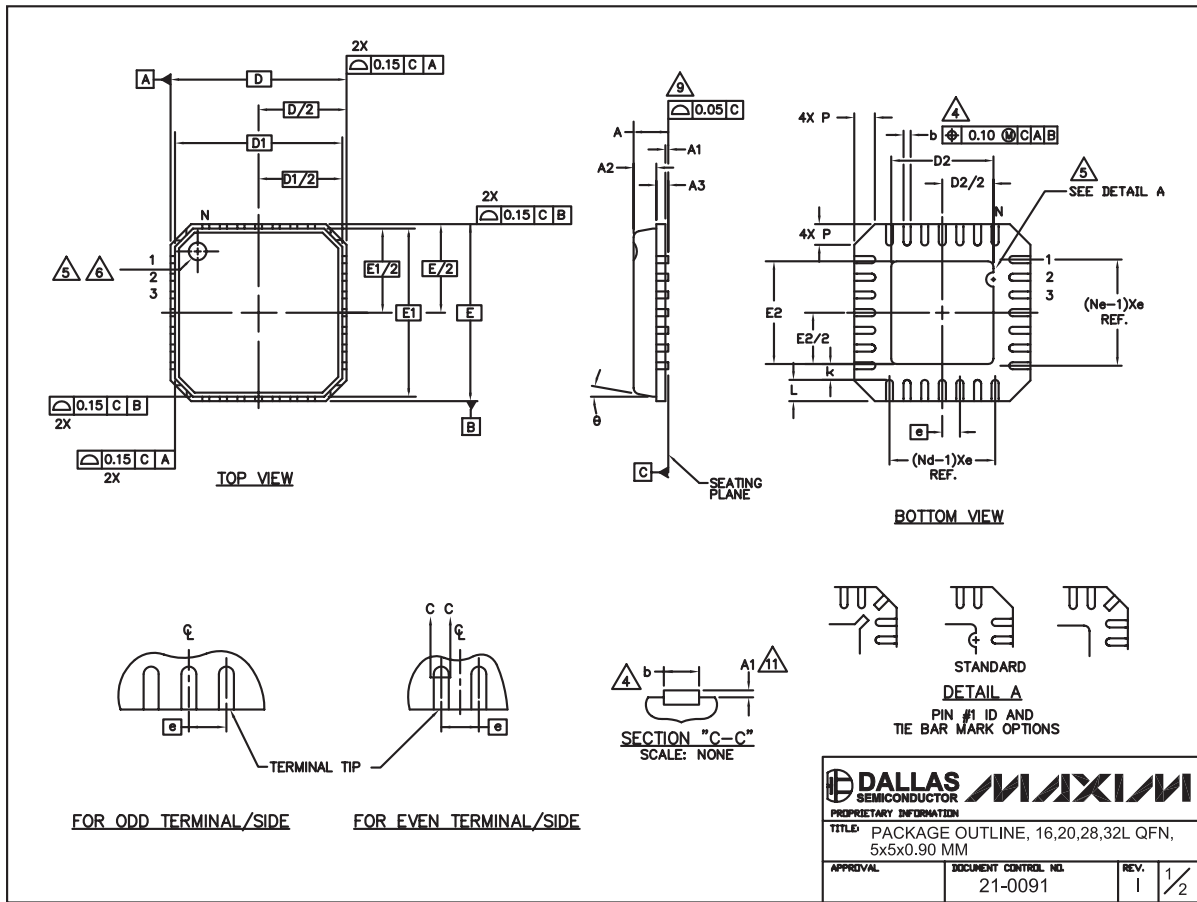
MAX3013



+1.2V to +3.6V, 0.1μA, 100Mbps, 8-Channel Level Translators

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)



+1.2V to +3.6V, 0.1µA, 100Mbps, 8-Channel Level Translators

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)

MAX3013

COMMON DIMENSIONS												
PKG SYMBOL	16L 5x5			20L 5x5			28L 5x5			32L 5x5		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.80	0.90	1.00	0.80	0.90	1.00	0.80	0.90	1.00	0.80	0.90	1.00
A1	0.00	0.01	0.05	0.00	0.01	0.05	0.00	0.01	0.05	0.00	0.01	0.05
A2	0.00	0.65	1.00	0.00	0.65	1.00	0.00	0.65	1.00	0.00	0.65	1.00
A3	0.20 REF			0.20 REF			0.20 REF			0.20 REF		
b	0.28	0.33	0.40	0.23	0.28	0.35	0.18	0.23	0.30	0.18	0.23	0.30
D	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10
D1	4.75 BSC			4.75 BSC			4.75 BSC			4.75 BSC		
E	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10
E1	4.75 BSC			4.75 BSC			4.75 BSC			4.75 BSC		
e	0.80 BSC			0.65 BSC			0.50 BSC			0.50 BSC		
k	0.25	—	—	0.25	—	—	0.25	—	—	0.25	—	—
L	0.35	0.55	0.75	0.35	0.55	0.75	0.35	0.55	0.75	0.30	0.40	0.50
N	16			20			28			32		
ND	4			5			7			8		
NE	4			5			7			8		
P	0.00	0.42	0.60	0.00	0.42	0.60	0.00	0.42	0.60	0.00	0.42	0.60
ϕ	0"		12"	0"		12"	0"		12"	0"		12"

EXPOSED PAD VARIATIONS						
PKG. CODES	D2			E2		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
G1655-3	2.95	3.10	3.25	2.95	3.10	3.25
G2055-1	2.55	2.70	2.85	2.55	2.70	2.85
G2055-2	2.95	3.10	3.25	2.95	3.10	3.25
G2855-1	2.55	2.70	2.85	2.55	2.70	2.85
G2855-2	2.95	3.10	3.25	2.95	3.10	3.25
G3255-1	2.95	3.10	3.25	2.95	3.10	3.25

NOTES:

1. DIE THICKNESS ALLOWABLE IS 0.305mm MAXIMUM (.012 INCHES MAXIMUM)
2. DIMENSIONING & TOLERANCES CONFORM TO ASME Y14.5M. — 1994.
3. N IS THE NUMBER OF TERMINALS.
Nd IS THE NUMBER OF TERMINALS IN X-DIRECTION & Ne IS THE NUMBER OF TERMINALS IN Y-DIRECTION.
4. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.20 AND 0.25mm FROM TERMINAL TIP.
5. THE PIN #1 IDENTIFIER MUST BE EXISTED ON THE TOP SURFACE OF THE PACKAGE BY USING INDENTATION MARK OR INK/LASER MARKED. DETAILS OF PIN #1 IDENTIFIER IS OPTIONAL, BUT MUST BE LOCATED WITHIN ZONE INDICATED.
6. EXACT SHAPE AND SIZE OF THIS FEATURE IS OPTIONAL.
7. ALL DIMENSIONS ARE IN MILLIMETERS.
8. PACKAGE WARPAGE MAX 0.05mm.
9. APPLIED FOR EXPOSED PAD AND TERMINALS. EXCLUDE EMBEDDED PART OF EXPOSED PAD FROM MEASURING.
10. MEETS JEDEC MO220; EXCEPT DIMENSION "b".
11. APPLIED FOR EXPOSED PAD AND TERMINALS. EXCLUDE EMBEDDING PART OF EXPOSED PAD FROM MEASURING.
12. THIS PACKAGE OUTLINE APPLIES TO ANVIL SINGULATION (STEPPED SIDES).

DALLAS SEMICONDUCTOR		MAXIM	
PROPRIETARY INFORMATION			
TITLE: PACKAGE OUTLINE, 16,20,28,32L QFN, 5x5x0.90 MM			
APPROVAL	DOCUMENT CONTROL NO.	REV.	2/2
	21-0091	1	

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